

1700V N-Channel Silicon Carbide Power MOSFET

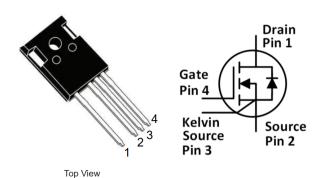
Features:

- High blocking voltage with low on-resistance
- High speed switching with low capacitance
- High operating junction temperature capability
- Very fast and robust intrinsic body diode
- Kelvin gate input easing driver circuit design

Applications:

- Solar inverters
- UPS
- Motor drivers
- High voltage DC/DC converters
- Switch mode power supplies

Package:



Part Number Package
DTN70N170SC4 TO247-4

Absolute Maximum Ratings (T_c=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions		
V _{DS}	Drain-Source voltage	1700	V	V _{GS} =0V, I _D =100μA		
V_{GS}	Gate-Source voltage	-5 to 20	V	Recommended maximum		
I _D	Drain current (continuous)	70	Α	V_{GS} =20V, T_C =25°C		
ID	Drain current (continuous)	50	А	V _{GS} =20V, T _C =100°C		
I _{DM}	Drain current (pulsed)	145	Α	Pulse width limited by SOA		
Ртот	Total power dissipation	510	W	T _c =25°C		
T_{stg}	Storage temperature range	-55 to 175	°C			
Tı	T _J Operating junction temperature		°C			
		260	°C	Wave soldering only allowed		
Tι	Solder Temperature			at leads, 1.6mm from case		
				for 10 s		

Thermal Data

Symbol	Symbol Parameter		Unit
$R_{\theta(J-C)}$	Thermal Resistance from Junction to Case	0.436	°C/W



Electrical Characteristics (T_c=25°C unless otherwise specified)

Symbol	Parameter	Value			Unit	Test Conditions	
		Min.	Тур.	Max.			
l _{DSS}	Zero gate voltage drain current		5	100	μΑ	V _{DS} =1700V, V _{GS} =0V	
lgss	Gate leakage current		1	<u>+</u> 100	nA	V _{DS} =0V, V _{GS} =-5~20V	
			3.2		V	V _{GS} =V _{DS} , I _D =6mA	
V_{TH}	Gate threshold voltage		2.2			$V_{GS}=V_{DS}, I_{D}=6mA$ @ $T_{C}=175^{\circ}C$	
Ron	Static drain-source on-		40	55	m Ω	V _{GS} =20V, I _D =20A @T _J =25°C	
KON	resistance		80		mΩ	V _{GS} =20V, I _D =20A @T _J =175°C	
Ciss	Input capacitance		2750		pF		
C_{oss}	Output capacitance		106		рF	V _{DS} =800V, V _{GS} =0V,	
C_{rss}	Reverse transfer capacitance		5.2		pF	f=1MHz, V _{AC} =25mV	
E _{oss}	Coss stored energy		43		μJ	1	
Qg	Total gate charge		120		nC	V -000V I -20A	
Q_{gs}	Gate-source charge		25		nC	- V _{DS} =800V, I _D =20A, - V _{GS} =-5 to 20V	
Q_{gd}	Gate-drain charge		48		nC	VGS3 to 20V	
R_g	Gate input resistance		2.8		Ω	f=1MHz	
Eon	Turn-on switching energy		455.4		μͿ		
E _{OFF}	Turn-off switching energy		213.6		μͿ	V _{DS} =800V, I _D =30A,	
$t_{\text{d(on)}} \\$	Turn-on delay time		8.9			V _{GS} =-2 to 20V,	
t_r	Rise time		28.9		ns	$R_{G(ext)}=3.3\Omega$	
t _{d(off)}	Turn-off delay time	25.6			113	L=450μH	
t _f	Fall time		17.2				



Reverse Diode Characteristics (T_c=25°C unless otherwise specified)

Symbol	Parameter	Value			Unit	Test Conditions
		Min.	Тур.	Max.		
	Diode forward voltage		4.9		V	I _{SD} =20A, V _{GS} =0V
V _{SD}			4.4		V	I _{SD} =20A, V _{GS} =0V,
						T ₁ =175°C
t _{rr}	Reverse recovery time		44.4		ns	V _{GS} =-2V/+20V,
			010.0		0	I _{SD} =30A, V _R =800V,
Qrr	Reverse recovery charge		212.6		nC	di/dt=1000A/us,
I _{RRM}	Peak reverse recovery current		10.8		А	$R_{G(ext)}=10\Omega$ L=450 μ H



Typical Performance (curves)

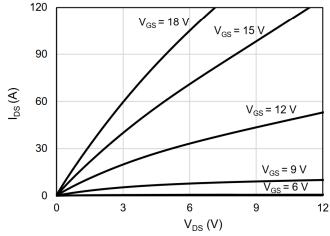


Figure 1: Output Characteristics T_J = -40°C

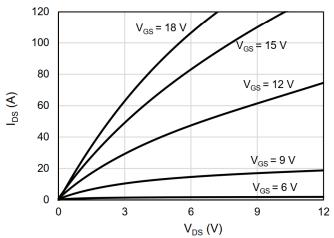


Figure 2: Output Characteristics $T_J = 25^{\circ}C$

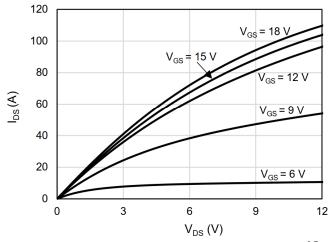
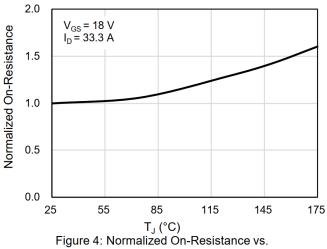
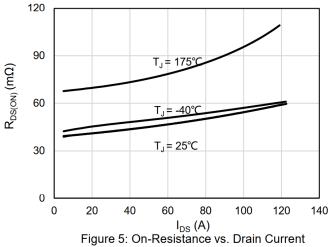


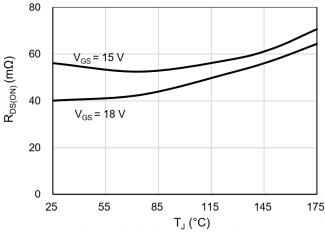
Figure 3: Output Characteristics $T_J = 175^{\circ}C$



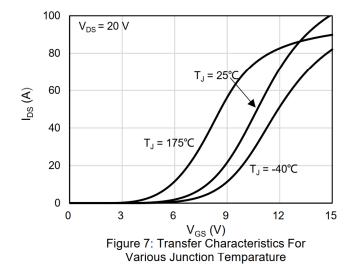
Temperature



For Various Temperatures



 $$T_{\rm J}\,(^{\circ}{\rm C})$$ Figure 6: On-Resistance vs. Temperature For Various Gate Voltage



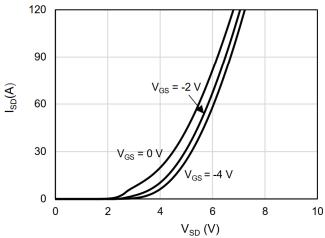
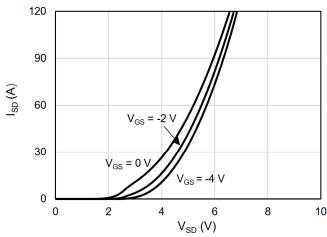
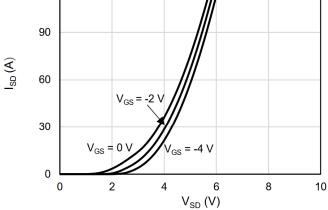


Figure 8: Body Diode Characteristics at -40°C

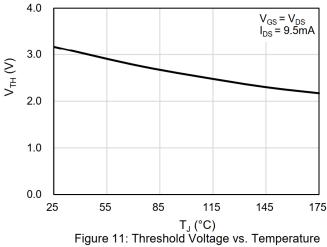


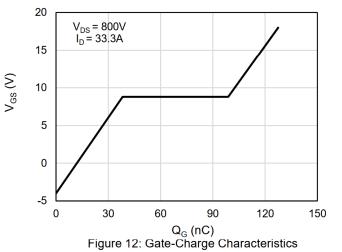


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Figure 9: Body Diode Characteristics at 25°C

Figure 10: Body Diode Characteristics at 175°C







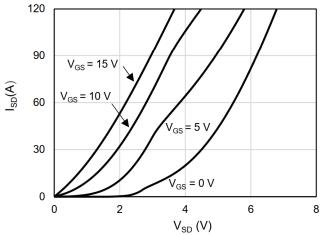


Figure 13: 3rd Quadrant Characteristics at -40°C

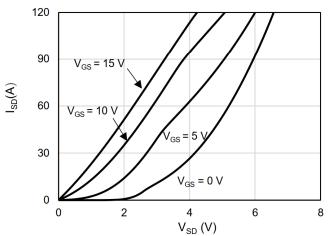


Figure 14: 3rd Quadrant Characteristics at 25°C

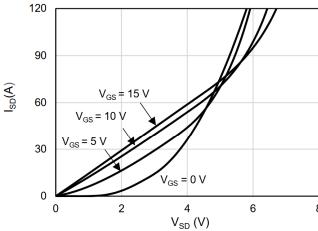
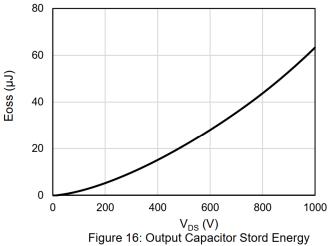
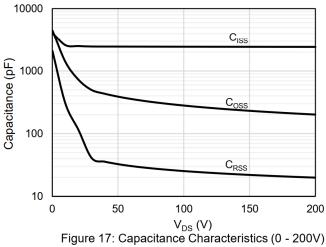
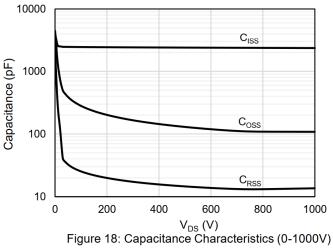


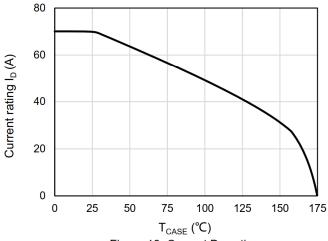
Figure 15: 3rd Quadrant Characteristics at 175°C













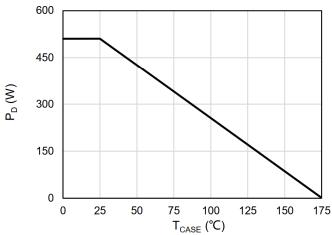


Figure 20: Maximum Power Disspation Derating vs CaseTemperature

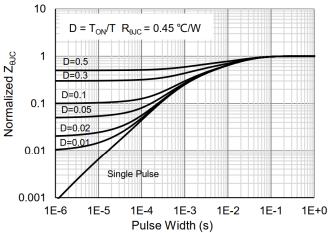
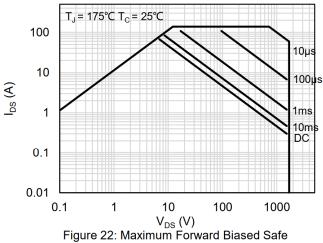
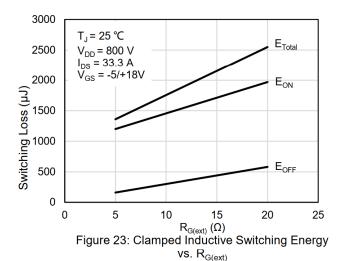


Figure 21: Normalized Maximum Transient Thermal Impedance



Operating Area



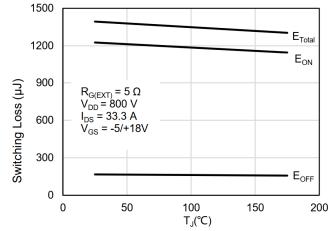
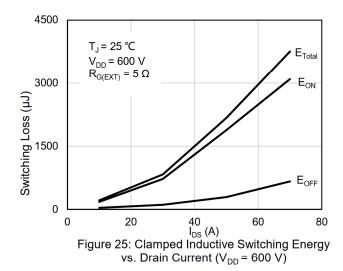


Figure 24: Clamped Inductive Switching Energy vs. T





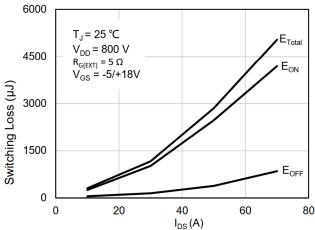
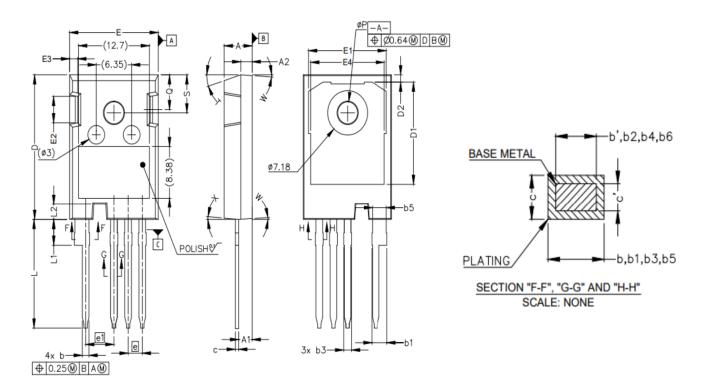


Figure 26: Clamped Inductive Switching Energy vs. Drain Current (V_{DD} = 800 V)



TO-247_4L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	4.50	5.02	5.50	E1	12.50	14.02	15.00
A1	2.00	2.40	2.80	E2	3.00	4.40	5.00
A2	1.80	2.00	2.30	E3	0.80	1.45	2.10
b'	0.90	1.20	1.40	E4	11.50	13.26	14.00
b	0.90	1.20	1.45	e		2.54BSC	
b1	2.15	2.67	3.10	e1		5.08BSC	
b2	2.15	2.67	3.05	N	4.00		
b3	0.90	1.30	1.80	L	16.00	17.57	19.00
b4	0.90	1.30	1.70	L1	3.47	4.19	4.87
b5	2.20	2.53	2.89	L2	2.05	2.50	2.95
b6	2.20	2.53	2.84	ФР	3.21	3.61	3.95
c'	0.48	0.60	0.75	Q	5.09	5.79	6.40
c	0.48	0.60	0.78	S	5.74	6.21	6.60
D	22.50	23.45	24.50	T	17.5°REF		
D1	15.50	16.55	18.10	W	3.5°REF		
D2	0.85	1.19	1.35	X	4°REF		
Е	15.00	15.94	17.00				

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